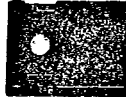


7-23-07

**SBP40-P SERIES**

SCHOTTKY RECTIFIER

**GENERAL INSTRUMENT**



**FEATURES**

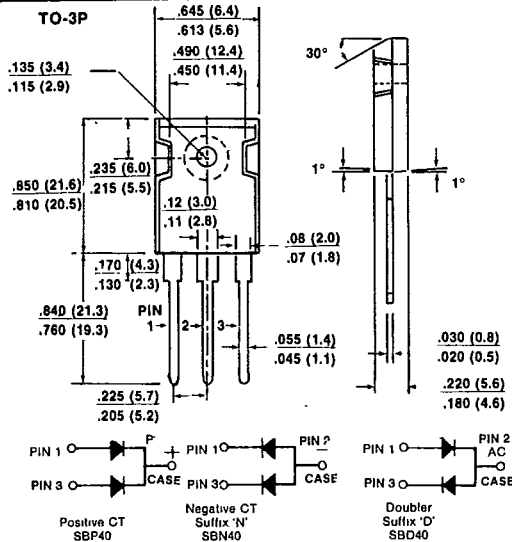
- Dual rectifier construction, positive center-tap
- Plastic material used carries Underwriters Laboratory Flammability Classification 94V-0
- Exceeds environmental standards of MIL-STD-19500
- Metal to silicon rectifier, majority carrier conduction
- Low power loss, high efficiency
- High current capability, low  $V_f$
- High surge capability
- Epitaxial construction
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

**MECHANICAL DATA**

Case: TO-3P  
 Terminals: Leads solderable per MIL-STD-202, Method 208  
 Polarity: As marked  
 Mounting Position: Any  
 Weight: .47 ounces, 13.2 ounces

**VOLTAGE RANGE**  
20 to 60 Volts

**CURRENT**  
40 Amperes



**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Ratings at 25°C ambient temperature unless otherwise specified.  
 Single phase, half wave, 60 Hz, resistive or inductive load.  
 For capacitive load, derate current by 20%.

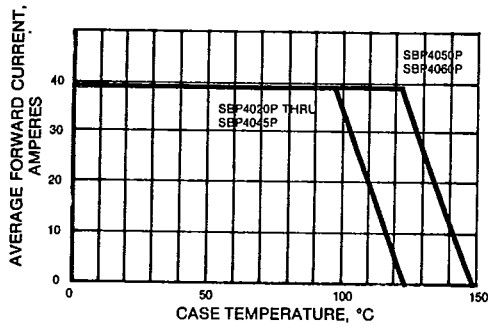
	SBP 4020P	SBP 4030P	SBP 4035P	SBP 4040P	SBP 4045P	SBP 4050P	SBP 4060P	UNITS
Maximum Recurrent Peak Reverse Voltage	20	30	35	40	45	50	60	V
Maximum RMS Voltage	14	21	24.5	28	31.5	35	42	V
Maximum DC Blocking Voltage	20	30	35	40	45	50	60	V
Maximum Average Forward Rectified Current See Fig. 1	40							A
Peak Forward Surge Current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	300							A
Maximum Instantaneous Forward Voltage Per Leg $I_f = 20A, T_c = 125^\circ C$ (Note 3) $I_f = 20A, T_c = 25^\circ C$	.60			.70				V
	.70			.80				V
Maximum Average Reverse Current at $T_c = 25^\circ C$ Rated DC Blocking Voltage per element $T_c = 100^\circ C$	10							mA
	100							mA
Typical Thermal Resistance $R_{\theta JC}$ (Note 1)	1.4							°C/W
Typical Junction Capacitance (Note 2)	1400					700		pF
Operating Temperature Range $T_c$	-65 to +125					-65 to +150		°C
Storage Temperature Range, $T_{stg}$	-65 to +150							°C

NOTES:  
 1. Thermal Resistance Junction to CASE. 3. 300µs Pulse Width, 2% Duty Factor.  
 2. Measured at 1 MHz and applied reverse voltage of 4.0 volts

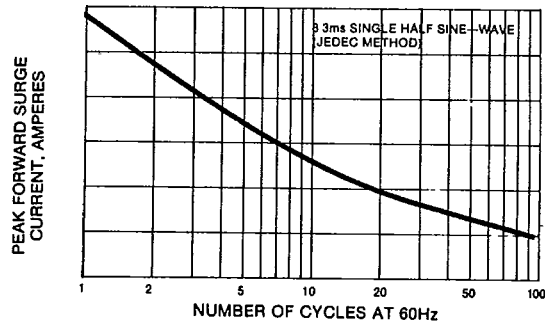
T-23-07

**RATING AND CHARACTERISTIC CURVES  
SBP40-P SERIES**

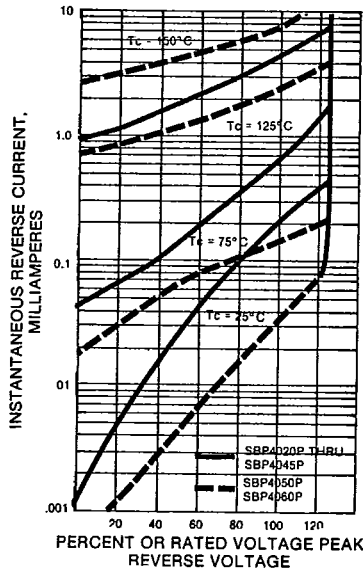
**FIG. 1 — FORWARD CURRENT DERATING CURVE**



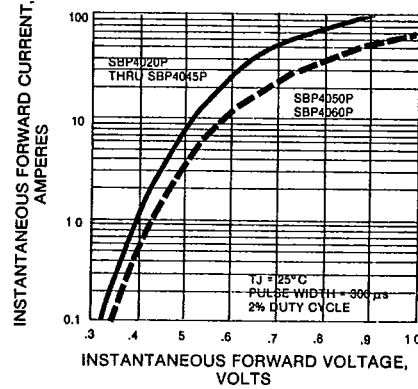
**FIG. 3 — MAXIMUM NON-REPETITIVE SURGE CURRENT**



**FIG. 2 — TYPICAL REVERSE CHARACTERISTICS**



**FIG. 4 — TYPICAL REVERSE CHARACTERISTICS**



**FIG. 5 — TYPICAL JUNCTION CAPACITANCE**

